

BFR92W

NPN Silicon RF Transistor*

- For broadband amplifiers up to 2 GHz and fast non-saturated switches at collector currents from 0.5 mA to 20 mA
- Complementary type: BFT92W (PNP)
- Pb-free (RoHS compliant) package 1)
- Qualified according AEC Q101
- * Short term description



ESD (Electrostatic discharge) sensitive device, observe handling precaution!

Туре	Marking	Pin Configuration			Package
BFR92W	P1s	1=B	2=E	3=C	SOT323

Maximum Ratings

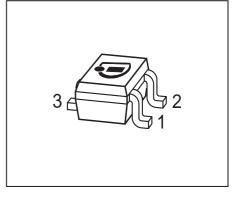
ol Value	Unit	
15	V	
20		
20		
2.5		
45	mA	
4		
280	mW	
150	°C	
-65 150		
-65 150		
	-65 150	

Thermal Resistance						
Parameter	Symbol	Value	Unit			
Junction - soldering point ³⁾	R _{th.IS}	≤ 230	K/W			

¹Pb-containing package may be available upon special request

 $^2{\cal T}_S$ is measured on the collector lead at the soldering point to the pcb

³For calculation of R_{th,IA} please refer to Application Note Thermal Resistance





Parameter	Symbol	Values			Unit
		min.	typ.	max.]
DC Characteristics	•				•
Collector-emitter breakdown voltage	V _{(BR)CEO}	15	-	-	V
<i>I</i> _C = 1 mA, <i>I</i> _B = 0					
Collector-emitter cutoff current	I _{CES}	-	-	10	μA
$V_{\rm CE}$ = 20 V, $V_{\rm BE}$ = 0					
Collector-base cutoff current	I _{CBO}	-	-	100	nA
$V_{\rm CB}$ = 10 V, $I_{\rm E}$ = 0					
Emitter-base cutoff current	I _{EBO}	-	-	100	μA
$V_{\rm EB}$ = 2.5 V, $I_{\rm C}$ = 0					
DC current gain-	h _{FE}	70	100	140	-
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, pulse measured					

Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified



Parameter	Symbol		Unit				
		min.	typ.	max.			
AC Characteristics (verified by random sampling)							
Transition frequency	f _T	3.5	5	-	GHz		
<i>I</i> _C = 15 mA, <i>V</i> _{CE} = 8 V, <i>f</i> = 500 MHz							
Collector-base capacitance	C _{cb}	-	0.42	0.6	pF		
$V_{\rm CB}$ = 10 V, <i>f</i> = 1 MHz, $V_{\rm BE}$ = 0 ,							
emitter grounded							
Collector emitter capacitance	C _{ce}	-	0.27	-			
$V_{CE} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$,							
base grounded							
Emitter-base capacitance	C _{eb}	-	0.66	-			
$V_{\rm EB}$ = 0.5 V, f = 1 MHz, $V_{\rm CB}$ = 0 ,							
collector grounded							
Noise figure	F				dB		
$I_{\rm C}$ = 2 mA, $V_{\rm CE}$ = 6 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$,							
<i>f</i> = 900 MHz		-	1.4	-			
$I_{\rm C}$ = 2 mA, $V_{\rm CE}$ = 6 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$,							
<i>f</i> = 1.8 GHz		-	2	-			
Power gain, maximum available ¹⁾	G _{ma}						
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$, $Z_{\rm L}$ = $Z_{\rm Lopt}$,							
<i>f</i> = 900 MHz		-	17	-			
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$, $Z_{\rm L}$ = $Z_{\rm Lopt}$,							
<i>f</i> = 1.8 GHz		-	11.5	-			
Transducer gain	S _{21e} ²				dB		
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 Ω ,							
<i>f</i> = 900 MHz		-	13.5	-			
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 Ω ,							
<i>f</i> = 1.8 MHz		-	8	-			

Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified

 ${}^{1}G_{\text{ma}} = |S_{21e} / S_{12e}| (k - (k^{2} - 1)^{1/2})$

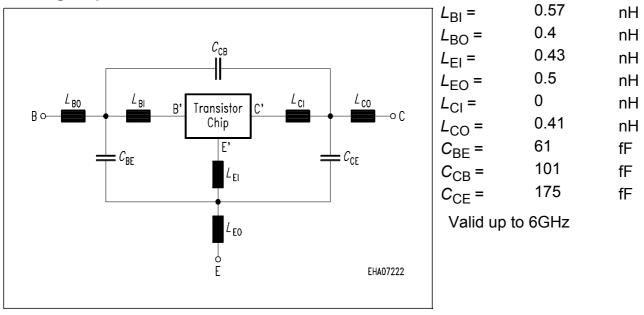


SPICE Parameter (Gummel-Poon Model, Berkley-SPICE 2G.6 Syntax):

Transistor Chip Data:									
IS =	0.1213	fA	BF =	94.733	-	NF =	1.0947	-	
VAF =	30	V	IKF =	0.46227	А	ISE =	129.55	fA	
NE =	1.9052	-	BR =	10.729	-	NR =	0.8983	-	
VAR =	14.599	V	IKR =	0.01	А	ISC =	0.75557	fA	
NC =	1.371	-	RB =	14.998	Ω	IRB =	0.01652	mΑ	
RBM =	7.8145	Ω	RE =	0.29088	-	RC =	0.13793	Ω	
CJE =	10.416	fF	VJE =	0.70618	V	MJE =	0.34686	-	
TF =	26.796	ps	XTF =	0.3817	-	VTF =	0.32861	V	
ITF =	4.4601	mA	PTF =	0	deg	CJC =	946.47	fF	
VJC =	0.84079	V	MJC =	0.4085	-	XCJC =	0.13464	-	
TR =	1.2744	ns	CJS =	0	fF	VJS =	0.75	V	
MJS =	0	-	XTB =	0	-	EG =	1.11	eV	
XTI =	3	-	FC =	0.99545		TNOM	300	К	

All parameters are ready to use, no scalling is necessary. Extracted on behalf of Infineon Technologies AG by: Institut für Mobil- und Satellitentechnik (IMST)

Package Equivalent Circuit:



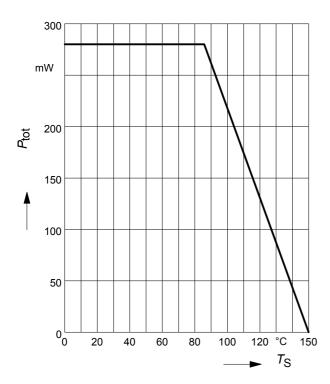
For examples and ready to use parameters please contact your local Infineon Technologies distributor or sales office to obtain a Infineon Technologies CD-ROM or see Internet: http://www.infineon.com



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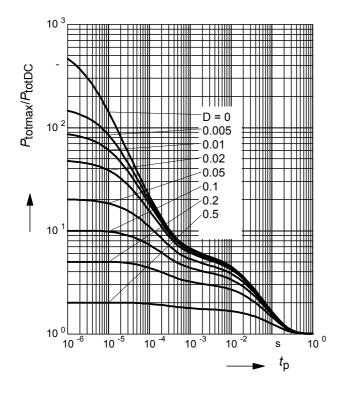
Total power dissipation $P_{tot} = f(T_S)$

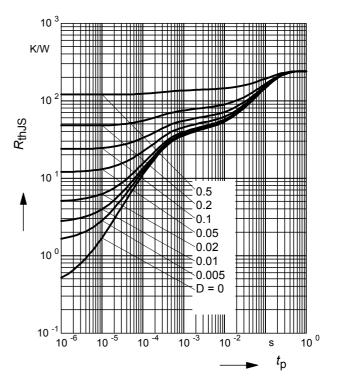
Permissible Pulse Load $R_{\text{thJS}} = f(t_p)$



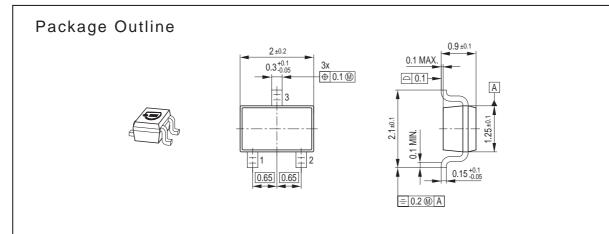
Permissible Pulse Load

 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

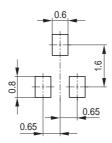


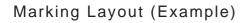


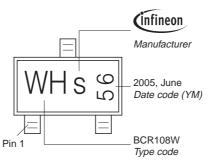




Foot Print

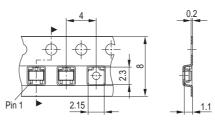






Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel





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